RoHS

COMPLIANT

HALOGEN FREE



Vishay Semiconductors

Hyperfast Rectifier, 60 A FRED Pt®



PRIMARY CHARACTERISTICS					
I _{F(AV)}	60 A				
V_{R}	300 V				
V _F at I _F	0.85 V				
t _{rr} typ.	28 ns				
T _J max.	175 °C				
Package	TO-247AD 3L				
Circuit configuration	Single				

FEATURES

- · Hyperfast recovery time
- Low forward voltage drop
- · Low leakage current
- · Soft recovery device
- 175 °C operating junction temperature
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>



VS-60APH03L-N3 series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for PDP and use in the output rectification stage for SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Cathode to anode voltage	V_{R}		300	V		
Continuous forward current	I _{F(AV)}	T _C = 103 °C	60	۸		
Single pulse forward current	I _{FSM}	$T_{J} = 25 ^{\circ}\text{C}, t_{p} = 10 \text{ms}$	450	А		
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C		

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	TEST CONDITIONS MIN. TYP.		MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	300	-	-		
		I _F = 30 A	-	1.0	1.25	- V	
Forward voltage	V _F	I _F = 60 A	-	-	1.45		
Forward voltage		I _F = 30 A, T _J = 125 °C	-	0.85	1.10		
		I _F = 60 A, T _J = 125 °C	-	-	1.30		
Reverse leakage current	I _R	$V_R = V_R$ rated	-	-	10		
neverse leakage current		$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{rated}$	-	-	100	μA	
Junction capacitance	C _T	V _R = 300 V	-	70	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	ı	3.5	-	nH	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time		$I_F = 1.0 \text{ A}, dI_F/dt = 10$	00 A/μs, V _R = 30 V	-	28	-		
		$I_F = 1.0 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		-	34	-	ns	
	t _{rr}	T _J = 25 °C		-	42	-	115	
		T _J = 125 °C		-	64	-		
Peak recovery current	I _{RRM}	T _J = 25 °C	$I_F = 60 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$	=	3.0	-	Α	
		T _J = 125 °C	V _R = 200 V	-	8.5	-	A	
Reverse recovery charge	0	T _J = 25 °C		-	65	-	nC	
	Q _{rr}	T _J = 125 °C		-	273	-	IIC	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C
Thermal resistance, junction to case	R _{thJC}		-	0.56	0.80	°C/W
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	C/VV
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.4	-	
Approximate Weight			=	6.0	-	g
Approximate Weight			-	0.22	-	OZ.
Mounting torque			6.0	-	12	kgf. cm
Mounting torque			(12)	-	(10)	(lbf.in)
Marking device		Case style TO-247AD 3L		60AF	H03L	

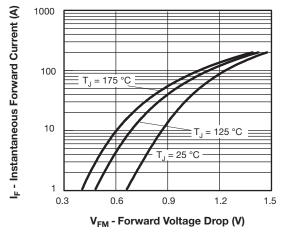


Fig. 1 - Typical Forward Voltage Drop Characteristics

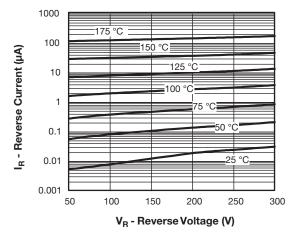


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

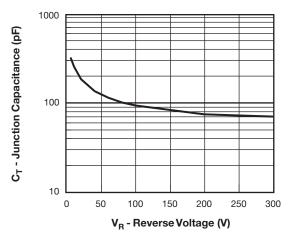


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

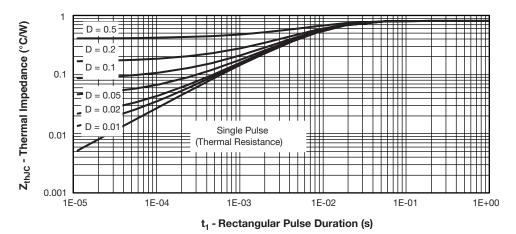


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

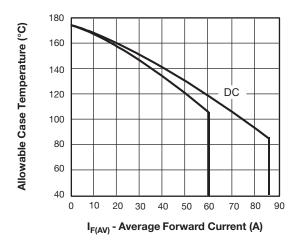


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

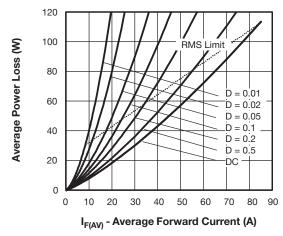


Fig. 6 - Forward Power Loss Characteristics



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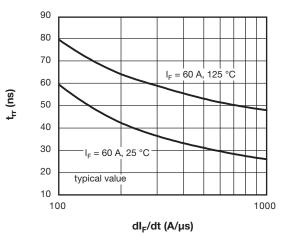


Fig. 7 - Typical Reverse Recovery vs. dl_F/dt

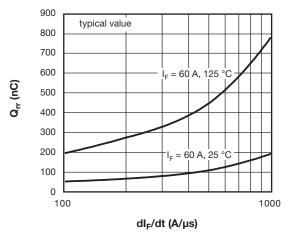
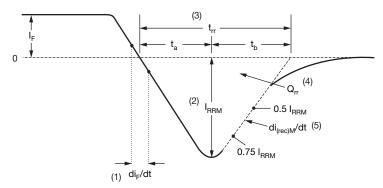


Fig. 8 - Typical Stored Charge vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_{rr}$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

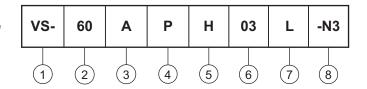
(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (60 = 60 A)

3 - Circuit configuration:

A = single diode

4 - P = TO-247

5 - H = hyperfast rectifier

6 - Voltage code (03 = 300 V)

7 - L = long lead

8 - -N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

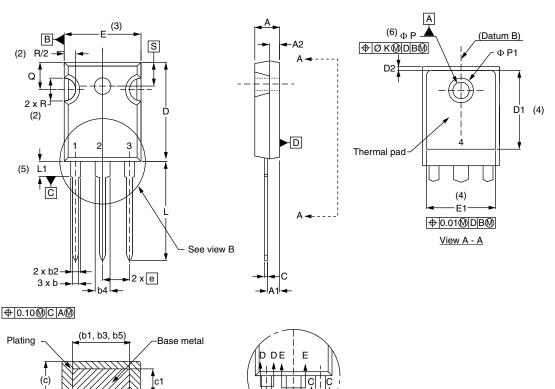
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-60APH03L-N3	25	500	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95626</u>				
Part marking information	www.vishay.com/doc?95007			
SPICE model	www.vishay.com/doc?96075			



TO-247AD 3L

DIMENSIONS in millimeters and inches



Section C - C, D - D, E - E							
SYMBOL	MILLIN	IETERS	INCHES		NOTES		
STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.65	5.31	0.183	0.209			
A1	2.21	2.59	0.087	0.102			
A2	1.50	2.49	0.059	0.098			
b	0.99	1.40	0.039	0.055			

0.039

0.065

0.065

0.102

0.102

0.015

0.015

0.776

0.515

0.053

0.094

0.092

0.135

0.133

0.035

0.033

0.815

(h h2 h4)

:5	

View B

SYMBOL	IVIILLIIV	MILLIMIL I LING		INOTILS		
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
D2	0.51	1.30	0.020	0.051		
E	15.29	15.87	0.602	0.625	3	
E1	13.46	-	0.53	-		
е	5.46	BSC	0.215	BSC		
ØΚ	0.2	254	0.010			
L	19.81	20.32	0.780	0.800		
L1	3.71	4.29	0.146	0.169		
ØΡ	3.56	3.66	0.14	0.144		
Ø P1	-	6.98	-	0.275		
Q	5.31	5.69	0.209	0.224		
R	4.52	5.49	0.178	0.216		
S	5.51 BSC		0.217 BSC			
•	•		•		•	

INCHES

MILLIMETERS

Notes

b1

b2

b3

b4

b5

С

с1

D

D1

(1) Dimensioning and tolerancing per ASME Y14.5M-1994

1.35

2.39

2.34

3.43

3.38

0.89

0.84

20.70

- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

3

- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1

0.99

1.65

1.65

2.59

2.59

0.38

0.38

19.71

13.08

- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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